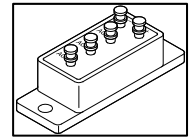


TECHNICAL DATA  
DATA SHEET 1052, REV. A

## THREE PHASE FULL WAVE RECTIFIER ASSEMBLY



**DESCRIPTION:** A 1000 VOLT, 40 AMP, 5000 NS 3-PHASE FULL WAVE RECTIFIER ASSEMBLY.

### MAXIMUM RATINGS

ALL RATINGS ARE AT  $T_C = 25\text{ C}$  UNLESS OTHERWISE SPECIFIED

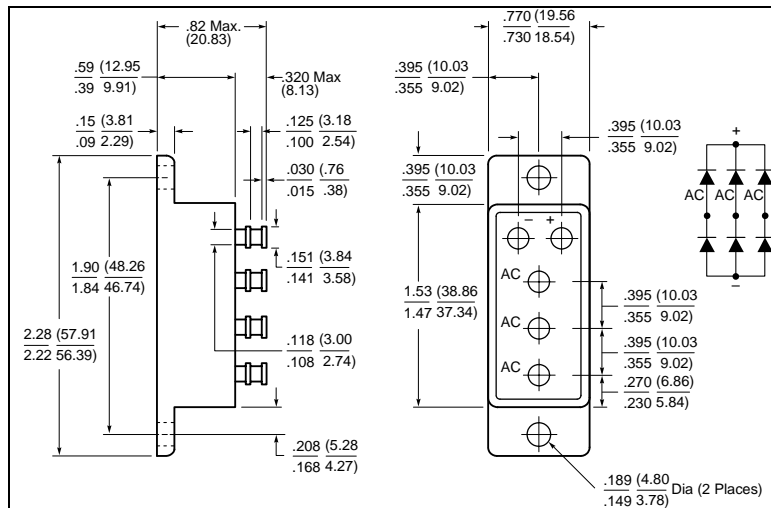
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE (PER LEG)	PIV	1000	Volts
MAXIMUM DC OUTPUT CURRENT ( $T_C = 55\text{ }^\circ\text{C}$ ) ( $T_C = 100\text{ }^\circ\text{C}$ )	$I_o$	40	Amps
		24	Amps
PEAK SINGLE CYCLE SURGE CURRENT $t_p = 8.3\text{ msec.}$ (PER LEG)	$I_{FSM}$	300	Amps
MAXIMUM THERMAL RESISTANCE	$R_{\theta JC}$	0.85	$^\circ\text{C/W}$
MAXIMUM JUNCTION TEMPERATURE RANGE	$T_J$	175	$^\circ\text{C}$
OPERATING AND STORAGE TEMPERATURE RANGE	$T_c, T_{stg}$	-55 to + 150	$^\circ\text{C}$

### ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP (PER LEG) ( $I_f = 10\text{ AMPS}$ )	$V_f$	1.2	Volts
MAXIMUM REVERSE CURRENT $I_r$ @ PIV (PER LEG) ( $T_C = 25\text{ }^\circ\text{C}$ ) $T_C = 100\text{ }^\circ\text{C}$ )	$I_r$	10	$\mu\text{A}$
		200	$\mu\text{A}$
MAXIMUM REVERSE RECOVERY TIME ( $I_f = 0.5\text{A}, I_r = 1.0\text{A}, t_{rr} = 0.25\text{A}$ )	$t_{rr}$	5000	ns

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**MECHANICAL DIMENSIONS: In Inches / mm**



\*Case--black anodized. Potting surface--uncontrolled

**Fig. 424**

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